

THIN TYPE CAMERA MODULE

FIELD OF THE INVENTION

The present invention is relating to a camera module, particularly to a thin type camera module comprises an image-sensing semiconductor assembly manufactured by Chip-On-Film technology.

BACKGROUND OF THE INVENTION

Application fields of a camera module are wide, such as digital camera, video telephone, video conference system. Normally the camera module includes a package having an image sensing chip (such as CMOS) inside an optical device for capturing image information. The camera module is converting the image information to the digital signal and transporting to a circuit board for identifying or storing the image information.

A conventional CCD image sensing module was disclosed in R.O.C. Taiwan Patent No. 492593 entitled "CCD and CMOS image capturing module". The CCD and CMOS image capturing module comprises a image sensing device which is electrically connecting to a circuit board. A lens holder is mounted on the circuit board and seals the image sensing device. Because that the circuit board forms a module circuit which is for connecting to the image sensing device, the process flow of the CCD and CMOS image capturing module is that firstly connecting the image sensing device to the circuit board, then fixing the lens holder and the circuit board. The CCD and CMOS image capturing module would cause the lens holder and the image sensing device misalignment, and capturing angle of the image sensing device is easy to deviate. Another improved structure of the CCD and CMOS image capturing module which is similar to the foregoing CCD and CMOS image capturing module are brought from the known patent. But the lens holder is connecting onto mold body of the image sensing device (CMOS or CCD). Besides, the lens holder is attached and sealed the top edge of the mold body of the image sensing device. However, the lens holder is connecting on

1 the image sensing device, the image sensing device has to sustain the weight of the whole
2 lens holder. The stability between the image sensing device and circuit board would be
3 poor.

4 Another conventional electric camera lens module was disclosed in R.O.C Taiwan.
5 Patent No. 372079 entitled "electric camera lens module". The electric camera lens
6 module comprises a lens holder and a photosensitive module, wherein a plane of the lens
7 holder disposes a hollow pillar which is set an adjustable cone, another plane of the lens
8 holder disposes a trough which is linking the hollow pillar. The photosensitive module
9 is installed in the trough, which comprises a filter, a hard substrate with pins and a
10 photosensitive chip, wherein the substrate has a through hole at corresponding the hollow
11 pillar for setting the filter. The photosensitive chip has a photosensitive surface
12 corresponding to the through hole and the pillar, and has a plurality of contact ends
13 contacted with pins of the substrate through the signal circuit of the substrate. When the
14 pins electrically contact with an exterior electronic device, the electric camera lens
15 module will start to capture image. Because of the photosensitive module is assembled
16 by the filter, the hard substrate and the photosensitive chip, wherein the photosensitive
17 chip is disposed at the bottom of the substrate in bare-chip configuration, so that
18 protection of the photosensitive chip is poor. The whole thickness of the electric camera
19 lens module is thicker, because the thickness of the photosensitive module has to consider
20 the thickness of the filter, the hard substrate and the photosensitive chip, and the length of
21 the pins of the hard substrate.

22 SUMMARY

23 The primary object of the present invention is to provide a thin type camera module
24 comprises an image-sensing semiconductor assembly which is manufacture by a
25 chip-on-film (COF) packaging method, so the thin type camera module is thinner.
26 Besides, a fixing board forms a recession for holding an image sensing chip in order to
27 achieve more thinner thin type camera module.

1 The second object of the present invention is to provide a thin type camera module
2 comprises an image-sensing semiconductor assembly which is manufacture by a COF
3 packaging method. An image sensing chip is flip-chip mounted on a COF wiring film,
4 so the reliability is better. And the COF wiring film is suited for continue mass
5 production the image-sensing semiconductor assembly to reduce the thin type camera
6 module running cost.

7 The third object of the present invention is to provide a thin type camera module
8 comprises an image-sensing semiconductor assembly with a COF wiring film. The
9 COF wiring film possesses all circuit design including module circuit for the thin type
10 camera module to integrate a module circuit of the thin type camera module in the
11 image-sensing semiconductor assembly so that an extra circuit substrate is not necessary.
12 The COF wiring film with module circuit has input/output terminals directly to let
13 image-sensing semiconductor assembly enables mounting of passive element. The
14 image-sensing semiconductor assembly could be connected to a fixing board or a lens
15 holder firstly for variedly process flow.

16 According to the thin type camera module of the present invention, which comprises
17 a fixing board, an image-sensing semiconductor assembly and a lens holder. The
18 image-sensing semiconductor assembly comprises a COF wiring film and an image
19 sensing chip. The the COF wiring film forms a plurality of connecting ends around a
20 window of the COF wiring film for flip-chip connecting. The connecting ends is
21 disposed on a surface of the COF wiring film. The image sensing chip has a
22 photosensitive surface with a plurality of bumps. The image sensing chip is flip-chip
23 mounted to the COF wiring film by electrically connecting the bumps and the connecting
24 ends, and the photosensitive surface of the image sensing chip is corresponding to the
25 window of the COF wiring film. Preferably, the COF wiring film includes a module
26 circuit for connecting passive element what the thin type camera module need. The lens
27 holder is mounted on the fixing board to form an airtight space. The image sensing chip

1 locates inside the airtight space and the photosensitive surface of the image sensing chip
2 is toward a light-pervious channel of the lens holder for capturing image.

3 DESCRIPTION OF THE DRAWINGS

4 Fig.1 is a cross-sectional view illustrating a thin type camera module of a first
5 embodiment of the present invention.

6 Fig.2 is a cross-sectional view illustrating an image-sensing semiconductor assembly
7 of the thin type camera module of the first embodiment of the present invention.

8 Fig.3 is a process flow chart of the thin type camera module of the first embodiment
9 of the present invention.

10 Fig.4 is a cross-sectional view illustrating a thin type camera module of a second
11 embodiment of the present invention.

12 Fig.5 is a cross-sectional view illustrating an image-sensing semiconductor assembly
13 of the thin type camera module of the second embodiment of the present invention.

14 DEATAILED DESCRIPTION OF THE PRESENT INVENTION

15 Referring to the drawings attached, the present invention will be described by means
16 of the embodiments below.

17 As showed in Fig.1, a thin type camera module 100 of a first embodiment of the
18 present invention comprises a fixing board 110, a lens holder 120 and an imaging-sensing
19 semiconductor assembly 130, wherein the fixing board 110 is a kind of hard material
20 without electrical transmitting function, such as BT substrate, FR-4 substrate, ceramic
21 substrate or metal plate. The lens holder 120 is mounted on the fixing board 110 to
22 form an airtight space to fix the imaging-sensing semiconductor assembly 130. The lens
23 holder 120 has a light-pervious channel 121 which forms a connecting portion 122, such
24 as inner thread of a screw, at an opening of the light-pervious channel 121 for connecting a
25 camera lens 140. The camera lens 140 has a lens 141 and its shape is like a cylindrical.
26 The camera lens 140 is fixed or connected to the lens holder 120 in adjustable type.

27 Referring to Fig.1 and 2, the imaging-sensing semiconductor assembly 130

1 comprises a COF (chip-on film) wiring film 131 and an image sensing chip 134, wherein
2 the COF wiring film 131 is flexible, such as polyimide (PI). The COF wiring film 131
3 has a first surface 131a, a second surface 131b and a window 132. The window 132 is
4 passing through the first surface 131a and the second surface 131b. In this embodiment,
5 the COF wiring film 131 has a plurality of metal wires forming on the first surface 131a.
6 The metal wires has a plurality of connecting ends 133 which are disposed around the
7 window 132 on the first surface 131a of the COF wiring film 131. The image sensing
8 chip 134 is optical sensing chip, CCD (charge coupled device), CMOS (complementary
9 metal oxide semiconductor) or photodiode, which is having a photosensitive surface 135.
10 A plurality of bumps 136, such as gold bumps, are formed on peripherals of the
11 photosensitive surface 135 for output terminals of the image sensing chip 134. The
12 image sensing chip 134 is flip-chip mounted on the COF wiring film 131, and its
13 photosensitive surface 135 is corresponding to the window 132 and the bumps 136 are
14 electrically connected with the connecting ends 133. Preferably, a sealant layer 137,
15 such as ACF (anisotropic conductive film), NCF (non-conductive film), UV past or
16 thermosetting filling past, is disposed around the window 132 of the COF wiring film 131
17 between the first surface 131a of the COF wiring film 131 and the photosensitive surface
18 135 of the image sensing chip 134. The sealant layer 137 encloses the bumps 136 of the
19 image sensing chip 134 and combines the COF wiring film 131 with the image sensing
20 chip 134 for improving reliability of electrically connecting of the connecting ends 133
21 and the bumps 136.

22 The image sensing chip 134 is disposed inside the airtight space which is formed by
23 the lens holder 120 and the fixing board 110. Inside the airtight space, it can be vacuum
24 state or inert gas filled, such as Nitrogen or Argon gas, for avoiding moisture invading
25 and effecting the image sensing chip 134 capturing image. In this embodiment, the
26 fixing board 110 forms a recession 111. The image sensing chip 134 is attaching on the
27 recession by an adhesive layer 112 (such as past or tape) which is formed at bottom

1 surface of the image sensing chip 134. The recession 111 assists the image sensing chip
2 134 in locating for aligning with the photosensitive surface 135 and the light-pervious
3 channel 121 of the lens holder 120. Perfectly, the lens holder 120 disposes a filter 123
4 which is also aligning with the light-pervious channel 121 and corresponding to the
5 photosensitive surface 135 of the image sensing chip 134. The filter 123 is used for
6 filtering out the infrared in order to avoid causing noise or false color. Besides, the COF
7 wiring film 131 includes a module circuit 138 which is formed on extending surface
8 which is not covered by the lens holder 120. The module circuit 138 is electrically
9 connecting at least an electric device 151, such as a passive component (selected from
10 resistant, inductance and capacitance) or a active component. A plurality of connection
11 fingers 152 are connected with the module circuit 138 of the COF wiring film 131 and
12 the image sensing chip 134, which are used for input/output terminals of the whole thin
13 type camera module 100 for electrically connecting to exterior electrical device.

14 The imaging-sensing semiconductor assembly 130 of the thin type camera module
15 100 of the present invention is manufactured by a Chip-On-Film (COF) packaging
16 method. The thin type camera module is thinner and suited for continuously mass
17 producing the image-sensing semiconductor assemblies to reduce the thin type camera
18 module running cost. The image sensing chip 134 is flip-chip mounted on the COF
19 wiring film 131. The connecting ends 133 of the COF wiring film 131, which are
20 disposed surrounding the window 132 on the first surface 131a for better stability of the
21 image sensing chip 134. And, the fixing board 110 forms the recession 111 for
22 installing the image sensing chip 134 and achieve forming a thinner thin type camera
23 module 100. In addition, the COF wiring film 131 of imaging-sensing semiconductor
24 assembly 130 can provide all circuit design of the thin type camera module 100 to
25 integrating the module circuit 138 of the image-sensing semiconductor assembly 130.
26 And the COF wiring film 131 is formed input/output terminals directly, so the hard
27 circuit substrate is not necessary. The COF wiring film 131 with the module circuit 138,

1 which is flexible and exposing out of the lens holder 120, so process flow of the thin type
2 of camera module 100 is various. The image-sensing semiconductor assembly 130
3 could be connected to the fixing board 110 or the lens holder 120 at first base on process
4 flow design to achieve elastic process flow because that the image-sensing semiconductor
5 assembly 130 is not necessary to electrically connect to the lens holder 120 and the fixing
6 board 110.

7 One of manufacturing process flows for the thin type camera module 100 of above
8 description is shown in Fig.3. The detailed description of the process flow of the thin
9 type camera module 100 is as following:

10 Firstly, a COF tape is provided in a step 11 of "providing a COF tape". The COF
11 tape is rolled in the reel, which comprises a plurality of mentioned-above COF wiring
12 films 131. Each first surface 131a of the COF wiring film 131 forms a plurality of metal
13 wires which include a plurality of connecting ends 133 disposed around the window 132
14 on the first surface 131a. Preferably, the metal wires are connecting with the module
15 circuit 138.

16 Then, the imaging-sensing semiconductor assembly 130 is manufactured by a COF
17 packaging method in a step 12 of "manufacturing an imaging-sensing semiconductor
18 assembly from the COF tape". Peripherals of the photosensitive surface 135 of the
19 image sensing chip 134 are a plurality bumps 136 which are non-reflowable conductive
20 bumps such as gold, copper, aluminum or its alloy, or solder bumps. In this
21 embodiment, the bumps 136 are gold bumps for flip-chip mounted to the COF tape.
22 Then, the image sensing chips 134 are flip-chip mounted to the COF tape. Preferably,
23 prior to the flip-chip mounting step, a sealant layer 137 such as an ACF or a NCF is
24 coated. The photosensitive surface 135 of the image sensing chip 134 is corresponding
25 the window 132 and face down, and the face surface 131a of the COF wiring film 131 is
26 face up for flip-chip mounting the image sensing chip 134 on the COF wiring film 131.
27 In one embodiment, the sealant layer 137 is an ACF, the bumps 136 could not be

1 necessary to bond with the connecting ends 133 actually. The bumps 136 are
2 electrically connected to the connecting ends 133 vertically by conductive particles of the
3 ACF sealant layer 137. The sealant layer 137 encloses the bumps 136 for protecting the
4 bumps and improving reliability of electrically connecting of the connecting ends 133
5 and the bumps 136. Perfectly, at least an electric device 151 is surface-mounted to the
6 module circuit 138 of the COF wiring film 131 for constituting whole module circuit 138
7 and electrical functions in the imaging-sensing semiconductor assembly 130. So the
8 COF tape can package the pluralities of image-sensing semiconductor assemblies 130
9 continuously, then the COF tape is singulated to get image-sensing semiconductor
10 assemblies 130 for next step of process flow of the thin type camera module 100.

11 Then, the image-sensing semiconductor assembly 130 is fixed to the fixing board
12 110 in a step 13 “mechanically connecting the image-sensing semiconductor assembly to
13 a fixing board”. The fixing board 110 has a recession 111. The adhesive layer 112 is
14 prepared in the recession 111 for adhering the image sensing chip 134. The recession
15 111 assists the image sensing chip 134 in fixing the image sensing chip 134 and the
16 capturing angle in position, meanwhile, providing a thinner module.

17 Then, the lens holder 120 is connecting to the fixing board 110 to form an airtight
18 space in a step 14 of “mechanically connecting a lens holder to the fixing board”. The
19 image sensing chip 134 is located inside the airtight space for avoiding dust invading it.
20 The lens holder 120 has a light-pervious channel 121 which is connecting a camera lens
21 140 at a opening of the light-pervious channel 121. Preferably, the lens holder 120
22 includes a filter 123 which is aligning with the light-pervious channel 121. The
23 photosensitive surface 135 of the image sensing chip 134, the filter 123 of the lens holder
24 120 and the lens 141 of the camera lens 140 are forming on the light-pervious channel
25 121 and corresponding each other for capturing image. In the process flow of the thin
26 type camera module 100 of above description, the image-sensing semiconductor
27 assembly 130 is located on the fixing board 110 and the recession 111 of the fixing board

1 110 assists the image sensing chip 134 in locating for the photosensitive surface 135 of
2 the image sensing chip 134 corresponding to the filter 123 and lens 141 in order to align
3 correctly and get right capturing angle.

4 As showed in Fig.4, a thin type camera module 200 of a second embodiment of the
5 present invention comprises a fixing board 210, a lens holder 220 and an imaging-sensing
6 semiconductor assembly 230, wherein the fixing board 210 is a kind of hard substrate
7 without electrical function. The lens holder 220 is mounted on the fixing board 210 to
8 form an airtight space. The lens holder 220 has a light-pervious channel 221 which
9 forms a connecting portion 222 for connecting a camera lens 240. The imaging-sensing
10 semiconductor assembly 230 comprises a COF wiring film 231 and an image sensing
11 chip 134. The image sensing chip 134 is disposed insides the airtight space. The COF
12 wiring film 231 has a first surface 231a, a second surface 231b, a window 232 which
13 passes through the first surface 231a and the second surface 231b, and at least a
14 conductive via 239 disposed around the window 232. In this embodiment, the COF
15 wiring film 231 has a plurality of metal wires forming on the second surface 231b. The
16 metal wires includes a plurality of connecting ends 233 disposed on the first surface
17 231a around the window 232. The conductive vias 239 electrically connect the
18 connecting ends 233. Surrounding the photosensitive surface 235 of the image sensing
19 chip 234 are a plurality of bumps 236. In this embodiment, the bumps 236 are
20 reflowable solder bumps. Fig.5 is a cross-section view illustrating of the
21 imaging-sensing semiconductor assembly 230 after manufactured by a chip-on-film
22 packaging method. The photosensitive surface 235 of the image sensing chip 234 is
23 face-down and corresponding to the window 232 of the COF wiring film 231 during
24 flip-chip mounting step. The first surface 231a of the COF wiring film 231 is face-up
25 and the image sensing chip 234 is flip-chip mounted on the COF wiring film 231. The
26 bumps 236 electrically connect the connecting ends 233. Preferably, a sealant layer
27 237 is formed surrounding the windows 232 of the COF wiring film 231 after flip-chip

1 mounting. In this embodiment, the sealant layer 237 is a thermosetting compound
2 such as UV past, transparent thermosetting liquid compoundt or underfilling material.
3 The sealant layer 237 fills the surrounding of the photosensitive surface 235 of the image
4 sensing chip 234 by capillarity, but it is not covering the active area of the photosensitive
5 surface 235. The sealant layer 237 encloses the bumps 236 for fixing the image sensing
6 chip 234and the COF wiring film 231 and for improving reliability of electrically
7 connecting of the connecting ends 233 and the bumps 236.

8 In this embodiment, thickness of the image sensing chip 234 is thinner by grinding
9 bottom surface of the image sensing chip 234 for providing a thinner module and a better
10 horizontal plane corresponding to the photosensitive surface 235. When the image
11 sensing chip 234 of the imaging-sensing semiconductor assembly 230 is disposed inside
12 the airtight space which is formed by the lens holder 220 and the fixing board 210, an
13 adhesive layer 211 (such as past or tape) is formed between the bottom surface of the
14 image sensing chip 234 and the fixing board 210 for fixing the image sensing chip 234 on
15 the fixing board 210. The image sensing chip 234 is steadier and having a steady
16 capturing angle. The photosensitive surface 235 of image sensing chip 234 is aligning
17 with the light-pervious channel 221 of the lens holder 220. The lens holder 220
18 comprises a filter 223 which is also aligning with the light-pervious channel 221 and
19 corresponding to the photosensitive surface 235 of the image sensing chip 234. The
20 photosensitive surface 235 of the image sensing chip 234, the filter 223 of the lens holder
21 220 and the lens 241 of the camera lens 240 are forming in the light-pervious channel 221
22 and corresponding each other for capturing image. In addition, the metal wires of the
23 COF wiring film 231 includes a module circuit 238 for electrically mounting at least a
24 passive component 251of the thin type camera module 200 in the imaging-sensing
25 semiconductor assembly 230. The module circuit 238 is formed on an extended surface
26 of the fixing board 210 which is not covered by the lens holder 220 for electrically
27 connecting the electric device 251. Connection fingers 252 are connected with the

1 module circuit 238 of the COF wiring film 231 and the image sensing chip 234, which
2 are used for input/output terminals of the whole thin type camera module 200.

3 Therefore, thickness of the thin type camera module 200 is thinner. The
4 imaging-sensing semiconductor assembly 230 of the thin type camera module 200 is
5 suited for continuously mass production to reduce the thin type camera module running
6 cost.

7 The whole circuit patterns of the thin type camera module 200 are integrated in the
8 imaging-sensing semiconductor assembly 230 with module circuit 238, so the extra
9 module substrate is not necessary. The COF wiring film 231 with module circuit 238 is
10 flexible and partially exposed out of the lens holder 220. The image-sensing
11 semiconductor assembly 230 could be mechanically connected to the fixing board 210 or
12 the lens holder 220 elastically for various process flow of the thin type camera module
13 200.

14 The above description of embodiments of this invention is intended to be illustrated
15 and not limiting. Other embodiments of this invention will be obvious to those skilled
16 in the art in view of the above disclosure.